

DESCRIPTION

The 2SK875 is N-channel MOS Field Effect Power Transistor designed for switching power supplies DC-DC converters.

FEATURES

- Suitable for switching power supplied, actuator controls, and pulse circuits.
- Low $R_{DS(on)}$
- No second breakdown

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature -55 to +150 °C

Channel Temperature 150 °C Maximum

Maximum Power Dissipation ($T_c = 25^\circ\text{C}$)

Total Power Dissipation 120 W

Maximum Voltages and Currents ($T_a = 25^\circ\text{C}$)

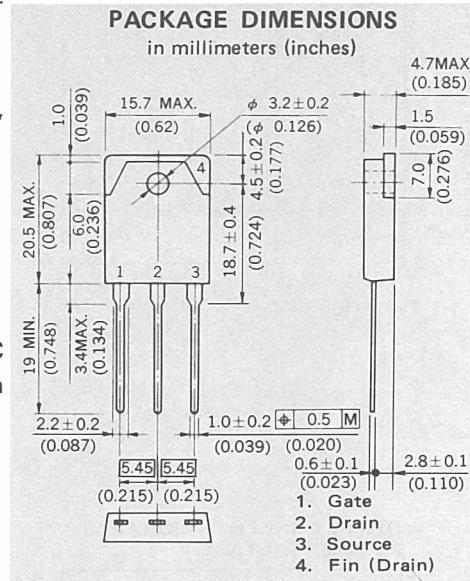
V_{DSS} Drain to Source Voltage 450 V

V_{GSS} Gate to Source Voltage ± 20 V

$I_{D(\text{DC})}$ Drain Current (DC) ± 12 A

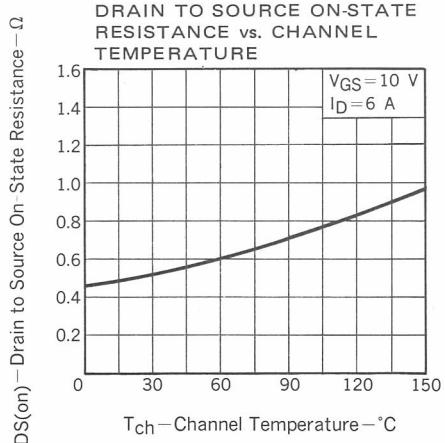
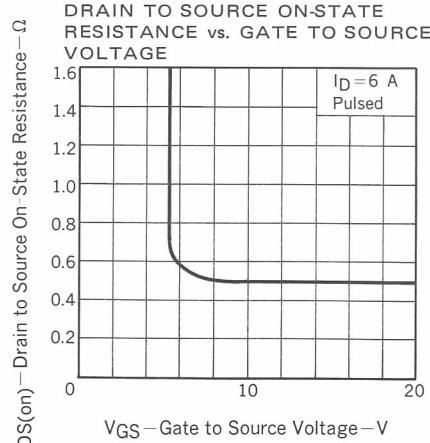
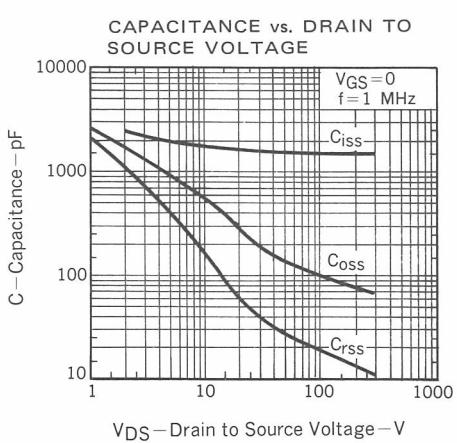
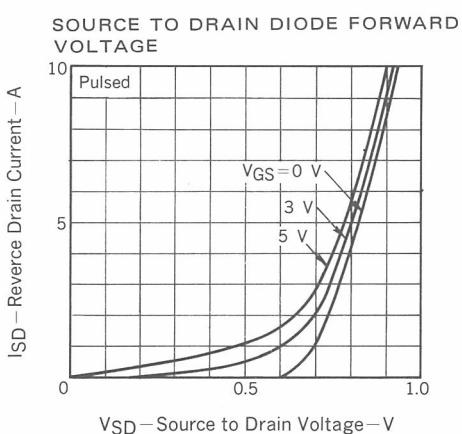
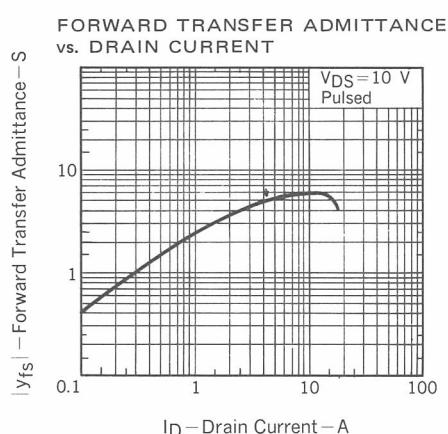
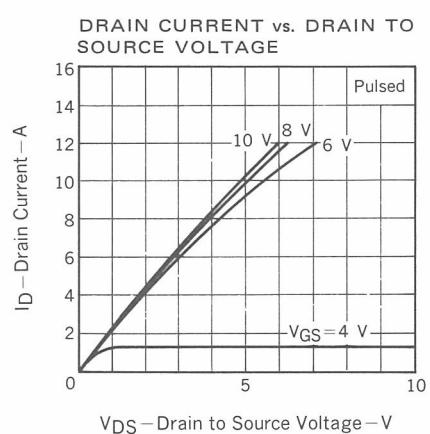
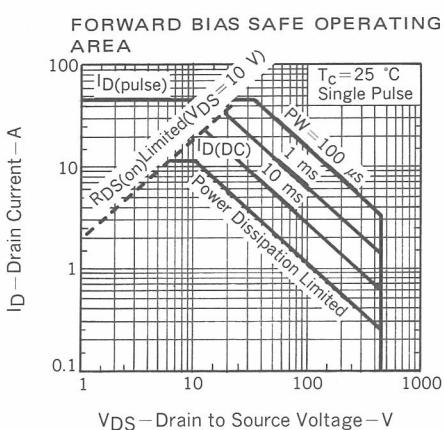
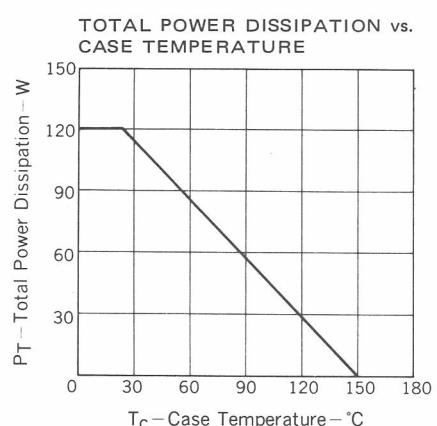
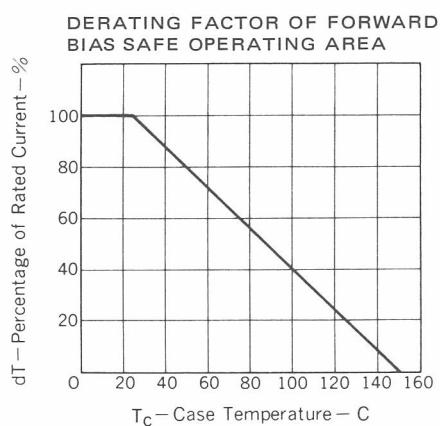
$I_{D(\text{pulse})}$ Drain Current (pulse)* ± 48 A

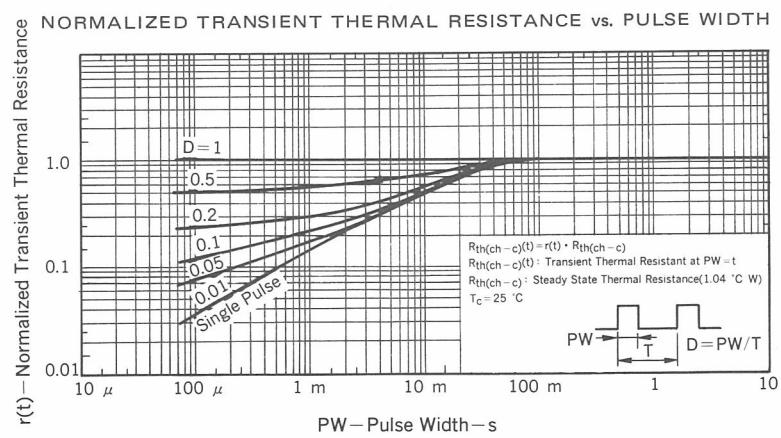
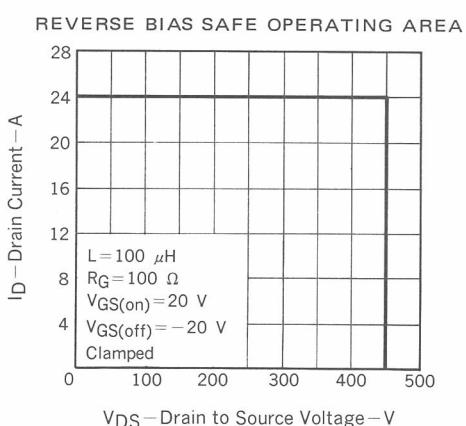
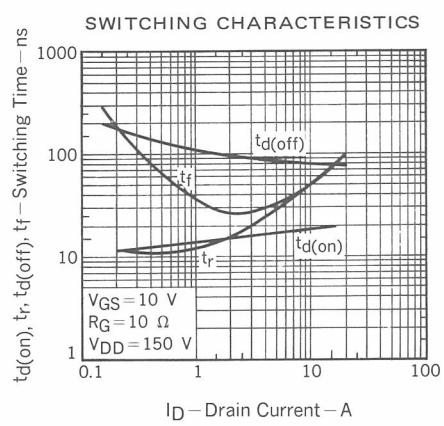
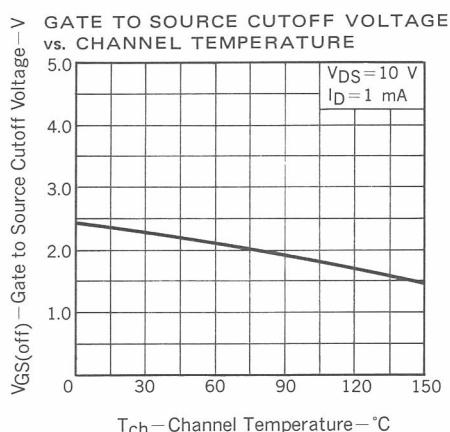
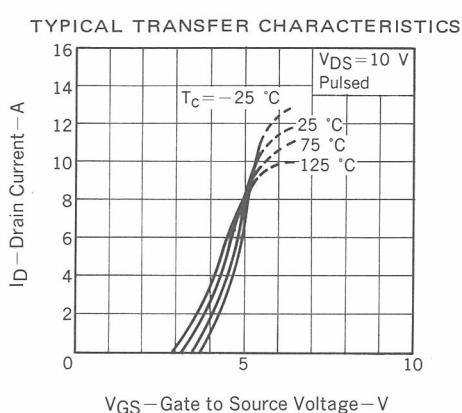
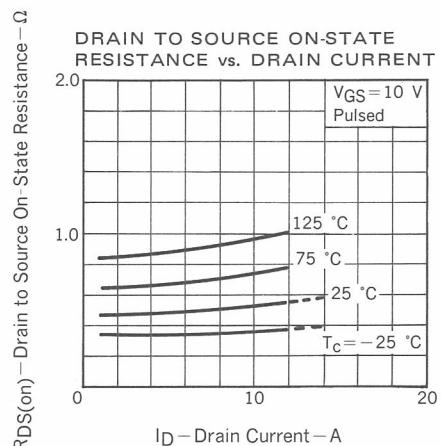
* $PW \leq 100 \mu\text{s}$, Duty Cycle $\leq 2\%$



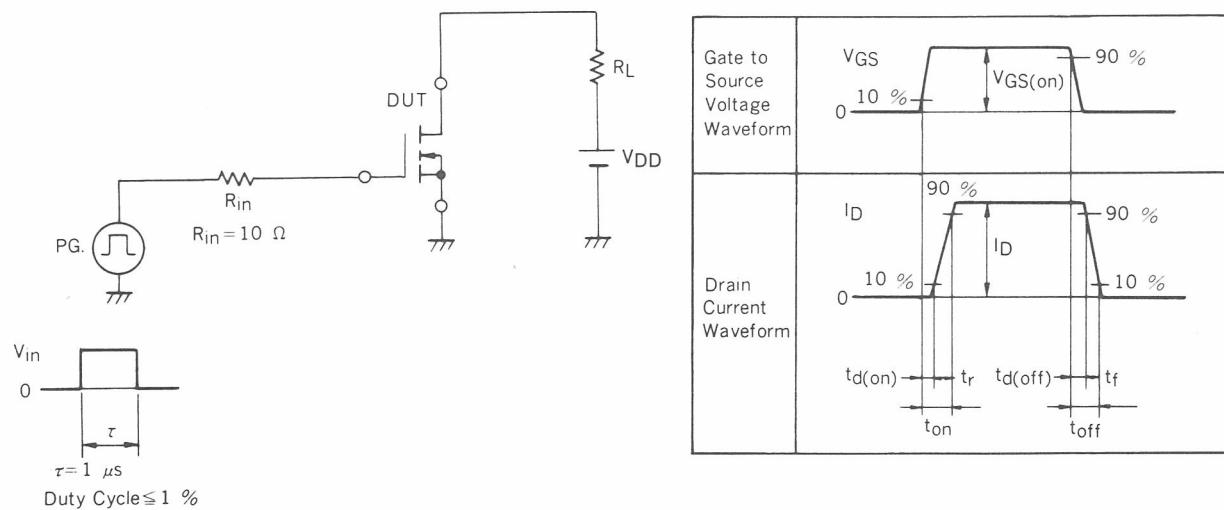
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
I_{DSS}	Drain Leakage Current			100	μA	$V_{DS} = 450 \text{ V}, V_{GS} = 0$
I_{GSS}	Gate to Source Leakage Current			± 100	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
$V_{GS(\text{off})}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
$ Y_{fs} $	Forward Transfer Admittance	5.0			S	$V_{DS} = 10 \text{ V}, I_D = 6 \text{ A}$
$R_{DS(\text{on})}$	Drain to Source On-State Resistance		0.5	0.60	Ω	$V_{GS} = 10 \text{ V}, I_D = 6 \text{ A}$
C_{iss}	Input Capacitance		2000		pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
C_{oss}	Output Capacitance		450		pF	
C_{rss}	Reverse Transfer Capacitance		120		pF	
$t_{d(\text{on})}$	Turn-On Delay Time	30			ns	$I_D = 6 \text{ A}, V_{DD} = 150 \text{ V}$ $V_{GS(\text{on})} = 10 \text{ V}$ $R_L = 25 \Omega$ $R_{in} = 10 \Omega$
t_r	Rise Time	50			ns	
$t_{d(\text{off})}$	Turn-Off Delay Time	100			ns	
t_f	Fall Time	50			ns	

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



SWITCHING TIME TEST CIRCUIT



CLAMPED INDUCTIVE TEST CIRCUIT

